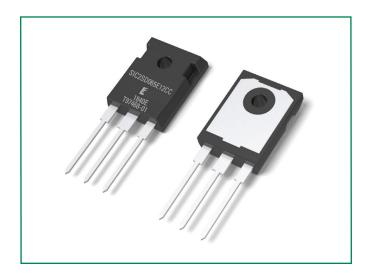
GEN2 SiC Schottky Diode LSIC2SD065E12CCA, 650 V, 12 A, TO-247-3L

LSIC2SD065E12CCA 650 V, 12 A SiC Schottky Barrier Diode





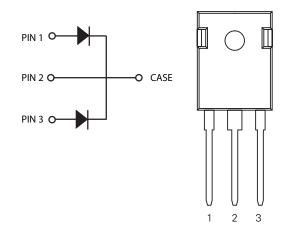
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. This diode series is ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C. maximum operating junction temperature
- · Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-247-3L



Applications

- · Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "Pb-free" logo = Pb Pb-free lead plating



Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	$V_{\rm B}$ $T_{\rm J} = 25{\rm ^{\circ}C}$		650	V	
Continuous Forward Current (Per Leg/Component)	l _F	T _C = 25 °C	18.5 / 37	А	
		T _C = 152 °C	6 / 12		
Non-Repetitive Forward Surge Current (Per Leg)	I _{FSM}	$T_{\rm C}$ = 25 °C, $t_{\rm P}$ = 10 ms, Half sine pulse	32	А	
Power Dissipation	P _{Tot}	T _C = 25 °C	75 / 150	W	
(Per Leg/Component)		T _C = 110 °C	32 / 64		
Operating Junction Temperature	T _J	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

Electrical Characteristics (T_J = 25 °C unless otherwise specified)

			Value			
Characteristics Symbol		Conditions	Min.	Тур.	Max.	Unit
Forward Voltage	\/	I _F = 6 A, T _J = 25 °C	-	1.5	1.8	V
	V _F	I _F = 6 A, T _J = 175 °C	-	1.85	-	
Reverse Current	I _R	$V_{_{\rm R}} = 650$ V, $T_{_{\rm J}} = 25$ °C	-	<1	50	μΑ
		$V_{_{\rm R}} = 650 \text{V, T}_{_{\rm J}} = 175 ^{\circ}\text{C}$	-	15	-	
Total Capacitance	С	$V_R = 1 V, f = 1 MHz$	-	300	-	pF
		V _R = 200 V, f = 1 MHz	-	39	-	
		V _R = 400 V, f = 1 MHz	-	28	-	
Total Capacitive Charge	Q _c	$V_R = 400 \text{ V}, Q_C = \int\limits_0^{V_R} C(v) dv$	-	20	-	nC

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance (Per Leg/Component)	R _{eJC}	2 / 1	°C/W

Figure 1: Typical Foward Characteristics

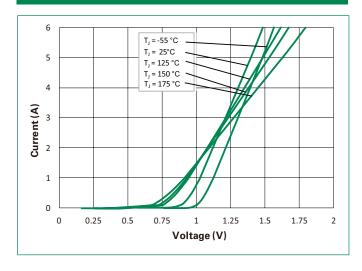


Figure 2: Typical Reverse Characteristics

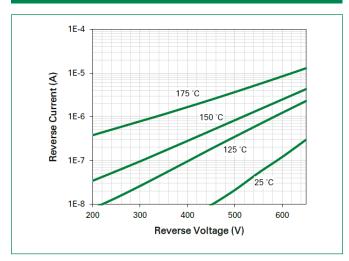




Figure 3: Power Derating

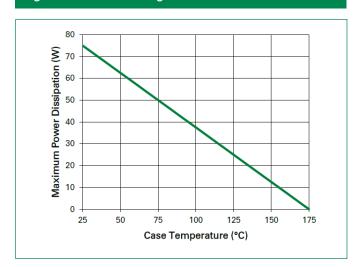


Figure 4: Current Derating

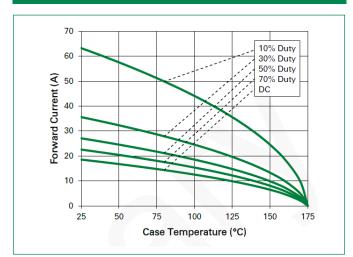


Figure 5: Capacitance vs. Reverse Voltage

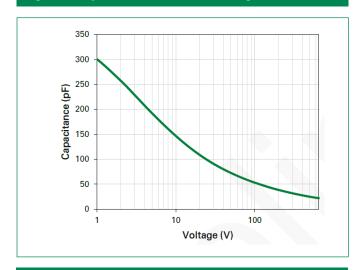


Figure 6: Capacitive Charge vs. Reverse Voltage

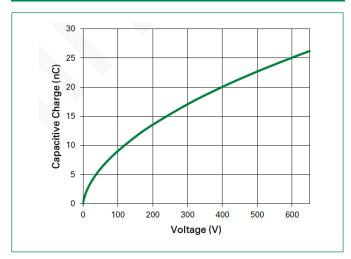


Figure 7: Stored Energy vs. Reverse Voltage

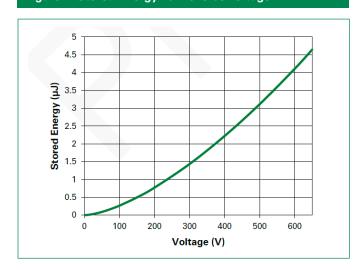
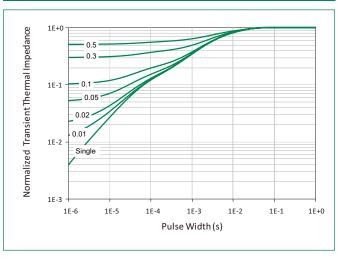
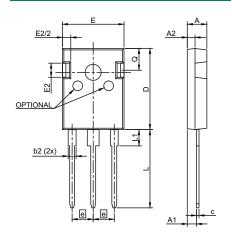


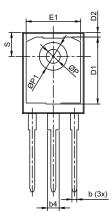
Figure 8: Transient Thermal Impedance



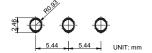
GEN2 SiC Schottky Diode LSIC2SD065E12CCA, 650 V, 12 A, TO-247-3L

Package Dimensions TO-247-3L





Recommended Hole Pattern Layout



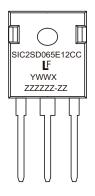
Notes:

- Dimensions are in millimeters
- Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side. These measured at the outermost extreme of plastic body.

 3.øP to have a maximum draft angle of 1.5° to the top
- 3.øP to have a maximum draft angle of 1.5° to the top of the part with a maximum hole diameter of 0.154"

Currele el	Millimeters				
Symbol	Min	Nom	Max		
А	4.80	5.03	5.20		
A1	2.25	2.38	2.54		
A2	1.85	1.98	2.11		
b	0.99	-	1.40		
b2	1.65	-	2.39		
b4	2.59	-	3.43		
С	0.38	0.64	0.89		
D	20.80	20.96	21.34		
D1	13.50	-	-		
D2	0.51	1.19	1.35		
е	5.44 BSC				
Е	15.75	15.90	16.13		
E1	13.06	14.02	14.15		
E2	4.19	4.32	4.83		
L	19.81	20.19	20.57		
L1	3.81	4.19	4.45		
øΡ	3.55	3.61	3.66		
øP1	7.06	7.19	7.32		
Q	5.49	5.61	6.20		
S	6.05	6.17	6.30		

Part Numbering and Marking System



SIC = SiC2 = Gen2

SD = Schottky Diode 065 = Voltage Rating (650 V)

E = TO-247-3L

12 = Current Rating (12 A)

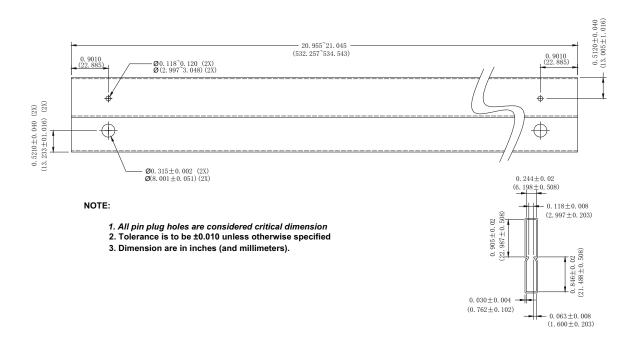
CC = Common Cathode Y = Year

WW = Week X = Special Code ZZZZZZ-ZZ = Lot Number

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065E12CCA	SIC2SD065E12CC	Tube (30pcs)	450

GEN2 SiC Schottky Diode LSIC2SD065E12CCA, 650 V, 12 A, TO-247-3L

Packing Specification TO-247-3L



Disclaimer Notice - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, Components intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse. Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Littelfuse manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT
54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK34B-TP
SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP
SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF
ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP
MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081 SB560 PMAD1108-LF SD103ATW-TP